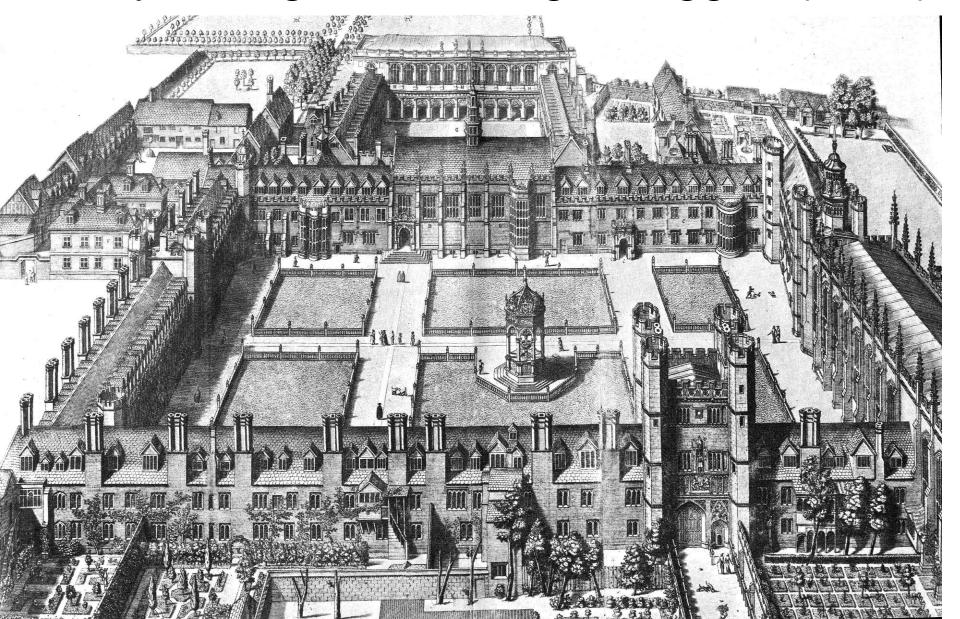
CHALCOGENIDE GLASSES: TRANSFORMATION AND CHANGE

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School on Glass-formers & Glasses: Bangalore (4-20 January 2010)

Trinity College, Cambridge: Loggan (1690)



LECTURE 1: Chalcogenides

- What are they?
- Why are they interesting?

Rigidity percolation

• Photoinduced (c-c, a-c, a-a) transformations

Some applications

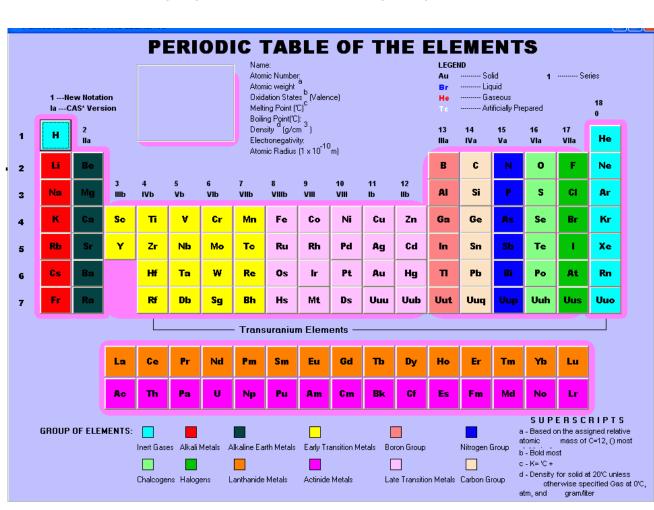
Chalcogenide Glasses

Chalcogen – Gp. VI element: {O}, S, Se, Te, {Po}

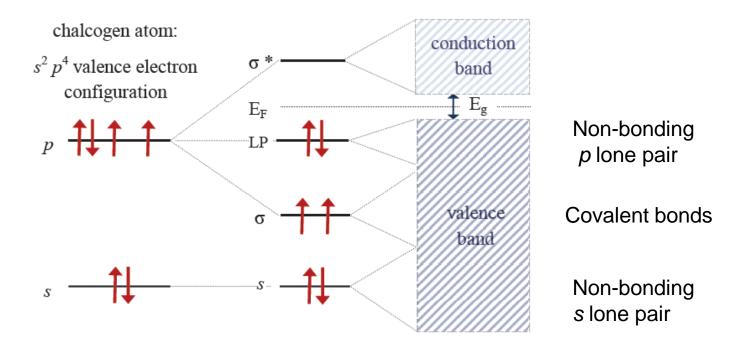
Chalcogenide –
 alloy of chalcogen
 & Gps. III,IV,V,VII...

- eg As₂S₃, GeSe₂, Ge₂Sb₂Te₅ etc

 glass-forming over wide composition ranges



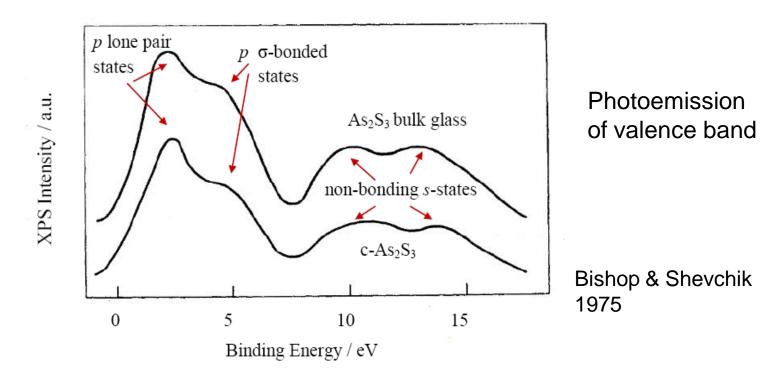
Chalcogens: Electronic structure



Atomic coordination is generally **2**-fold: 2 p- σ bonds

- although 3-fold coordination is also possible using *dative* bonding involving p- π lone-pair states

Chalcogenide Glasses: Electronic Structure



- NB 1) Electronic structure of binary, etc, *chalcogenide* glasses is very similar to that of pure *chalcogens*
 - 2) Electronic structure of *glasses* is very similar to *crystals*

Atomic Coordination of Chalcogenide Glasses '8-N Rule'

• Chalcogens (
$$\{O\}$$
, S, Se) = 2
(Te) = 2 (3)

• Pnictogens (P, As, Sb) = 3

• 'Tetragens' (Si, Ge) = 4

Halogens (Cl, Br, I) = 1

Phillips-Thorpe Constraint Theory

- Assume glass structure is a continuous network satisfying CNs, r_i, of constituent elements, i:
 - average CN = <*r*>

- Stretching constraints: <*r*>/2
- Bending constraints: 2<*r*> 3
- Total no. of constraints, $N_c = \{5 < r > /2\} 3$
 - if equals dimensionality, $N_d = 3$
- i.e. $\langle r_{cr} \rangle = 12/5 = 2.4$ 'optimal' CN

Liquid/Glass Anomalies at <r>=2.4

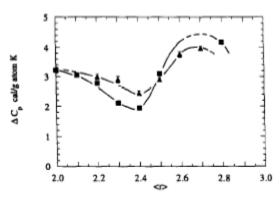


Fig. 10. ΔC_p versus $\langle r \rangle$ for binary Ge–Se and ternary Ge–Sb–Se systems. The ΔC_p values for the binary and the ternary are represented by \blacksquare and \blacktriangle , respectively. The curves are drawn as a guide to the eye. The maximum measured error is 1.8%.

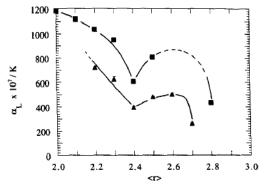
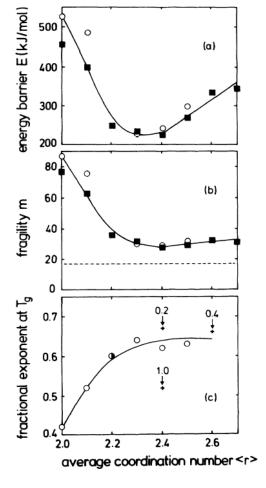


Fig. 4. Liquid state thermal expansion coefficient, α_L , versus $\langle r \rangle$ for the binary Ge-Se and ternary Ge-Sb-Se systems. The α_L values for the binary and the ternary are represented by \blacksquare and \blacktriangle , respectively. The curves are drawn as a guide to the eye. The maximum measured error is 3.5%.



Varshneya et al 1991

Boehmer & Angell 1994

Modulated DSC

Sinusoidal modulation of linear heating rate

- Jump in 'reversing heat flow': position $\rightarrow T_g$; jump height $\rightarrow \Delta C_p$
- 'non-reversing' (NR) heat flow peak:
 - \rightarrow non-equilibrium properties (e.g. ageing) peak area \rightarrow ΔH_{nr}

Relation between mDSC & Rigidity

1. 'Elastically flexible, floppy': <r> ~ 2

Narrow temperature width of NR peak

• ΔH_{nr} ages with time as stretched exponential

Relation between mDSC & Rigidity

2. 'Elastically rigid, stress-free': <r> ~2.4

• $\Delta H_{\rm nr} \sim 0$

Little ageing

Relation between mDSC & Rigidity

3. 'Elastically rigid, stressed': <r> ~ 3

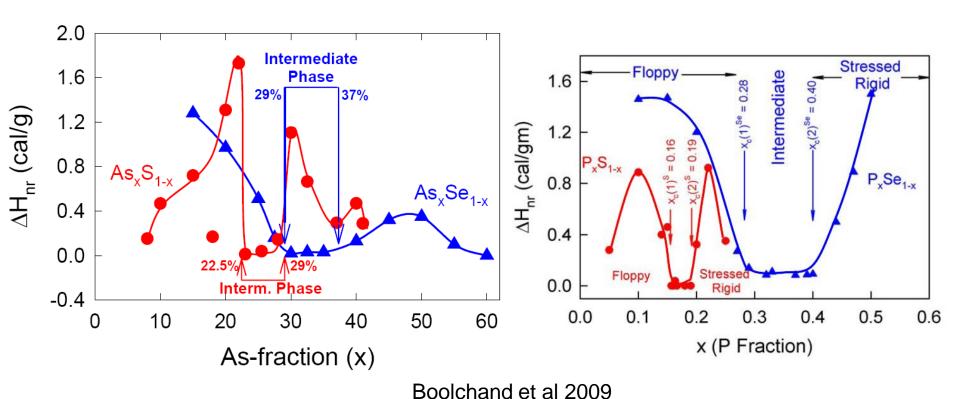
Broad, asymmetric NR peak with temperature

• ΔH_{nr} ages with time

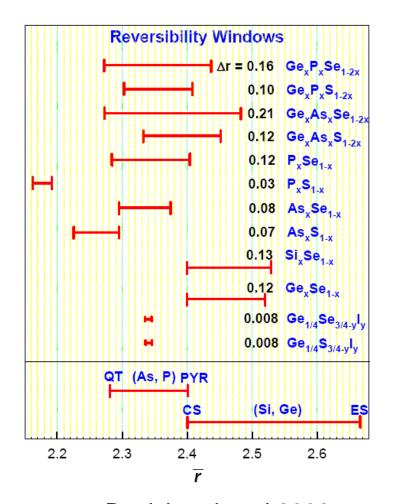
'Intermediate' ('Boolchand') Phase

Sulphide glasses

'Reversibility window' in compositional dependence of non-reversing heat flow



Universality of 'Reversibility Windows'?



Boolchand et al 2009

Reversibility windows do NOT all occur at <*r*> ~ 2.4

- indicative of nanoscale phase separation?
- or a failure of the model?(need to modify constraints)

Does the 'intermediate 'phase exist?

Arsenic Chalcogenides

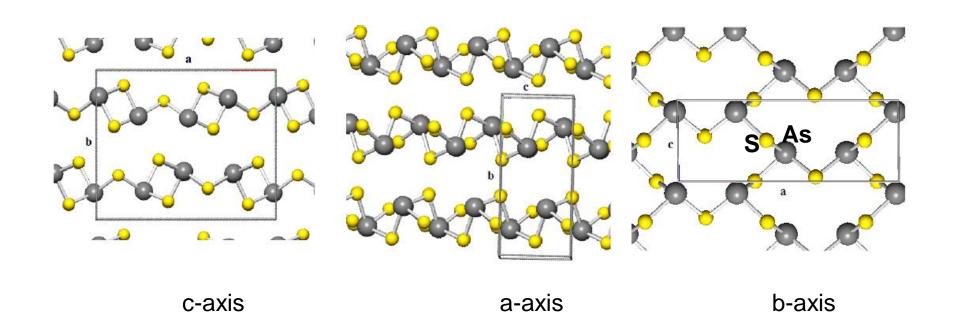
- For stoichiometry: As₂S₃,
- $\langle r \rangle = \{2x3 + 3x2\}/5 = 2.4 = \langle r_{cr} \rangle$
- → good glass former
- For stoichiometry: As_4S_4 , $< r > = {4x3 + 4x2}/8 = 2.5 > < r_{cr} >$ $\rightarrow N_c = 3.25 > N_d = 3$
 - 'overconstrained' if in network structure
 - → poor glass former (or another reason..)

Chalcogenide Structures: Networks or Molecular Aggregates?

- The low values of atomic coordination of chalcogens (2) and pnictogens (3) mean that glass structures can be either: 2-3D networks or 0D molecular clusters (VdW-bonded)
- E.g. structure of stoichiometric As₂S₃ consists of network of corner-shared AsS₃ pyramidal units
- But how are As atoms distributed in As-rich glasses – (non)randomly - in network/molecule?
- For possibilities, refer to crystals e.g. As-S

c-As₂S₃: orpiment

2D layer structure

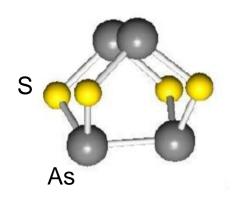


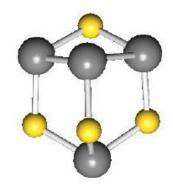
As-rich Molecular As-S Species

Molecules are approximately spherical

-real-life atomic model for hard-sphere systems

c-As₄S₄



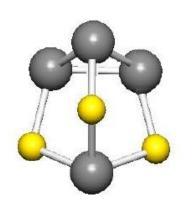


α,β- realgar

pararealgar

 (α,β) different packings)

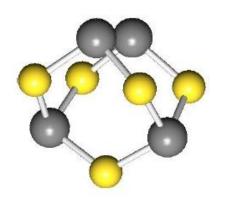
$c-As_4S_3$



'= para-realgar - S'

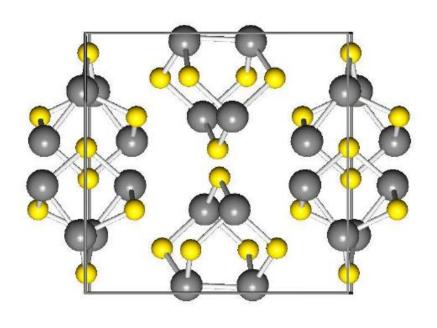
 α,β -dimorphite

c-As₄S₅: uzonite



'= α ,β-realgar + S'

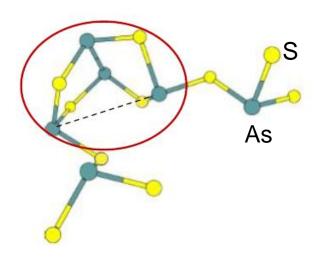
c-As₈S₉: alacranite



 As_4S_4 As_4S_5 As_4S_4

Realgar-like molecular fragment in network structure

Ab initio molecular-dynamics model of As₂S₃



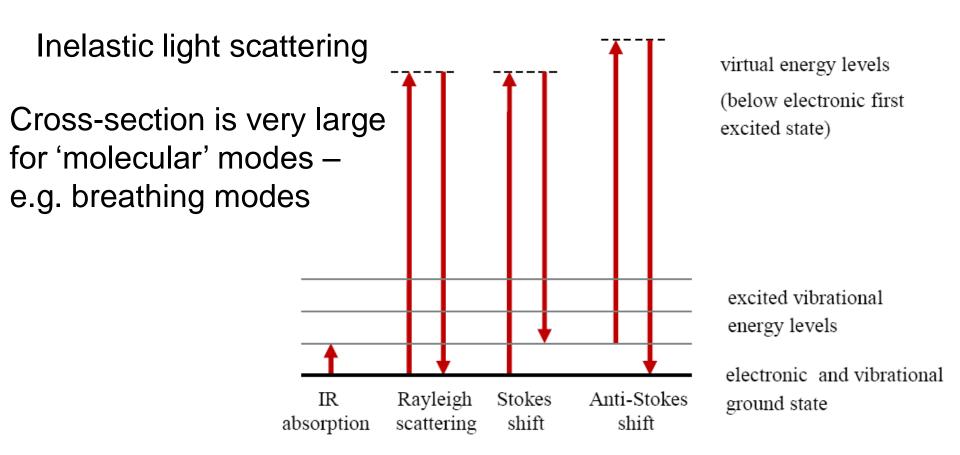
Ideally, expect stoichiometric glass to be chemically *ordered*

Does chemical disorder - (oriented) homopolar bond) -promote quasimolecular formation?

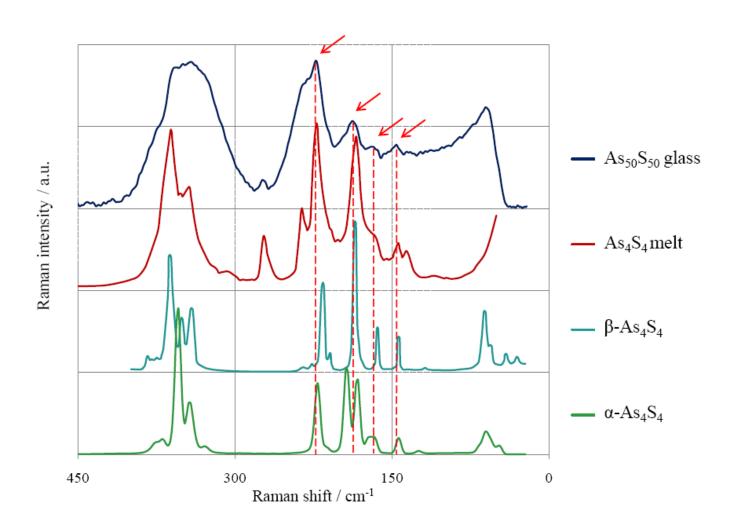
S. Simdyankin, S.R.E...., Phys. Rev. **B69**, 144202 (2004).

How to Detect Molecular Entities?

Raman Scattering from vibrational modes



Raman Spectra of AsS



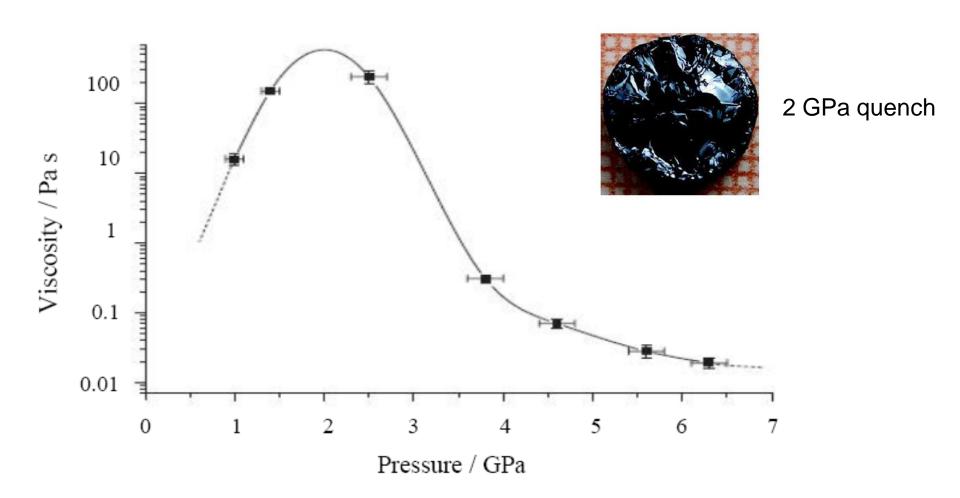
Glass Formation of AsS

 As₄S₄ (para-) realgar-like molecules, etc, are near-spherical

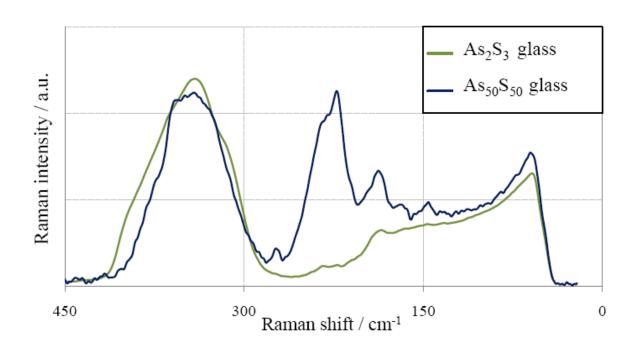
- Van der Waals interactions between molecules are spherically symmetrical
 - → low-viscosity molecular melts
 - bad glass-formation ability (ambient pressure)
 (limit normally 43% As)
 - (c.f. rare-gas/ Lennard-Jones systems)

Glass Formation of AsS

High-pressure quenching (Brazhkin et al 2009)



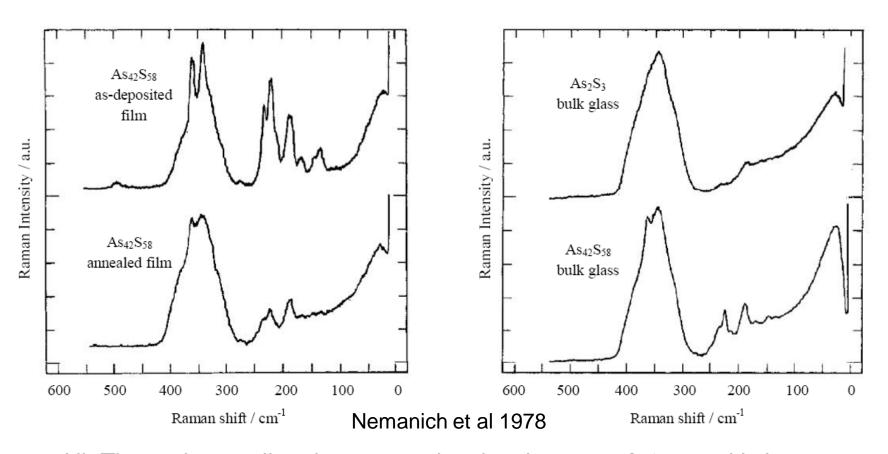
Molecular vs. Network As-S Glasses



As-S₃ pyramid Molecular modes stretch modes

Molecular character of a-As-S films

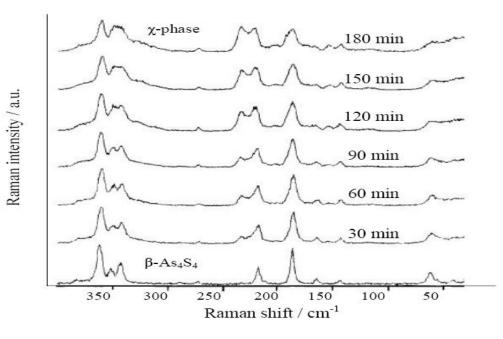
Molecular species are stable in precursor vapour



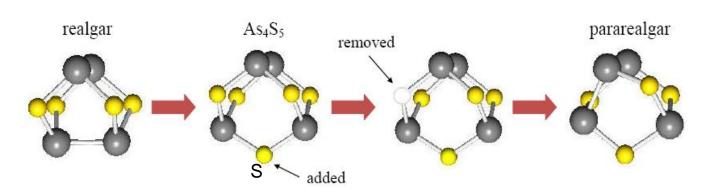
Nb Thermal annealing destroys molecular character → 'network' glass

Photoinduced *c-c* transformations: β-realgar → pararealgar

Bonazzi et al 1996



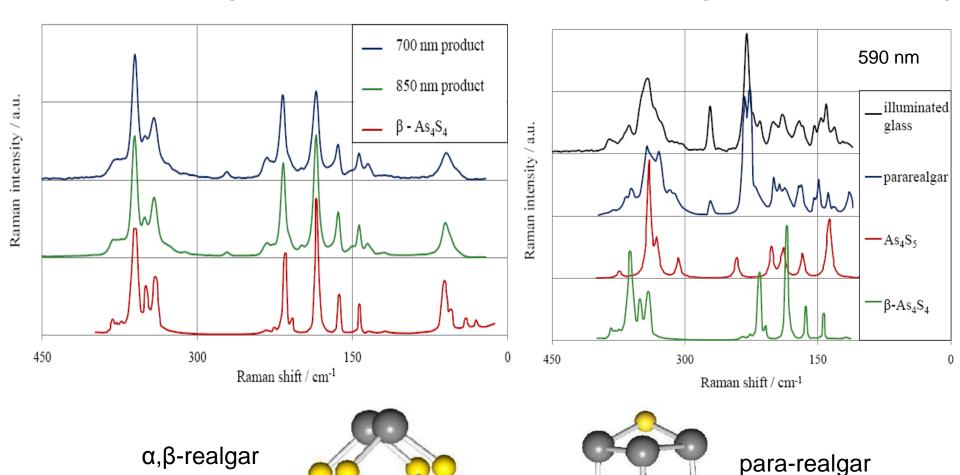
X-phase is intermediate, involving As₄S₅



Photocrystallization of As₄S₄ glass

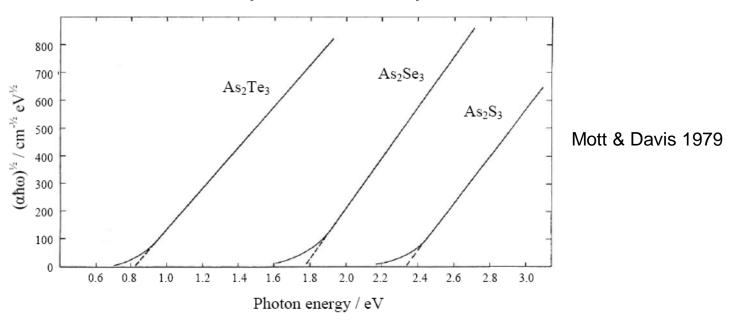
VdW 'bond-breaking → molecular reorientation

Bond-breaking → molecular reforming



Chalcogenide Glasses: Semiconductors

Optical Absorption



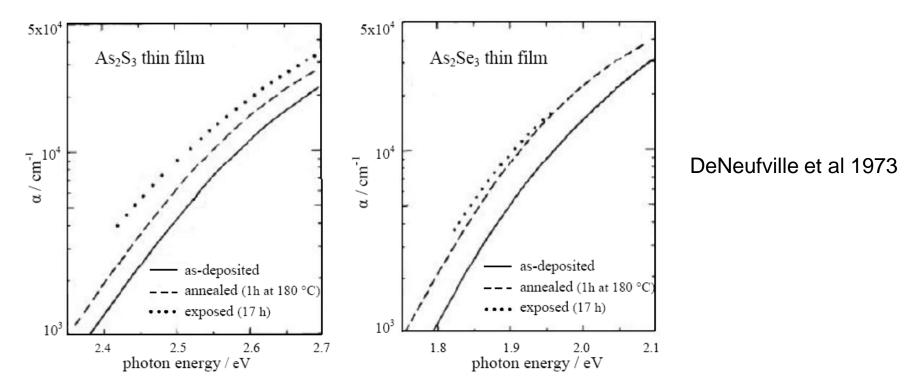
Bandgaps range from <1eV to >3eV: Te < Se < S << O

Photoinduced *a-a* Phenomena in Chalcogenide Glasses

- Bandgap-illumination changes can be:
 - metastable or transient
 - reversible or irreversible
 - scalar or vectoral

- structural
- optical ($\Delta \alpha$, Δn)
- chemical (etching rate).....

Amorphous-amorphous photoinduced changes



Photodarkening – redshift of optical absorption edge

Irreversible change from as-deposited state

- then reversible change from annealed state to new 'photo-state'

Photoinduced Changes

To paraphrase the Heineken beer advert:

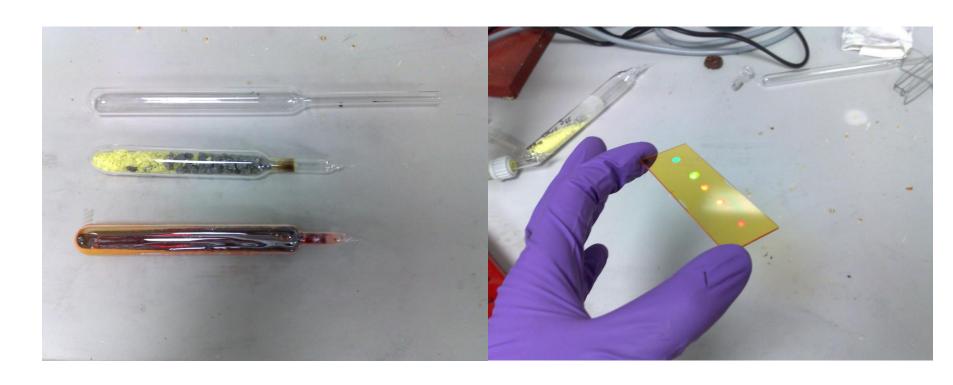
'Light can reach parts of the energy landscape no other stimulus can reach'

Photoinduced Optical Changes

- Refractive-index changes of Δn ~ 0.1 can be produced by bandgap illumination –
- 'direct' laser writing (no post-processing)
 - → 'buried' optical waveguides

 Or photoinduced changes in chemical-etching rate can produce 'ridge' optical waveguides

As₂S₃ Glass & Film

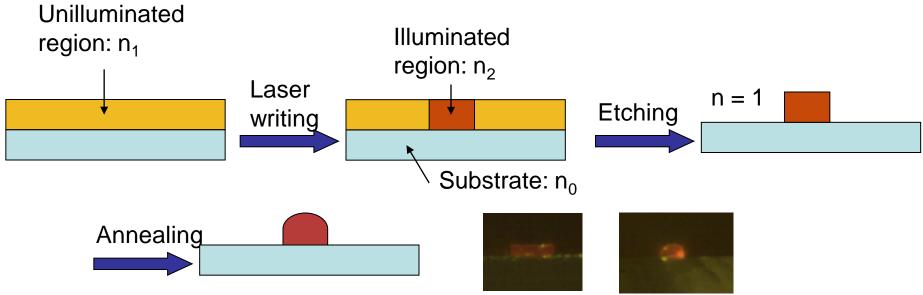


 $As + S \rightarrow g-As_2S_3$

a-As₂S₃ film with directly written Bragg gratings

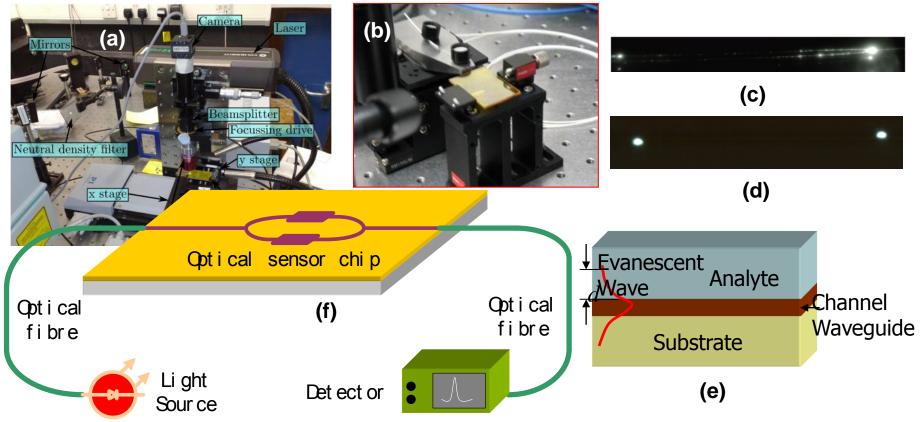
Sensor on a chip

- Chalcogenide glass (ChG) offers excellent transparency from visible to middle infrared
- Enhance the refractive-index difference (△n) by selective etching
- Smooth the waveguide surface by thermal annealing



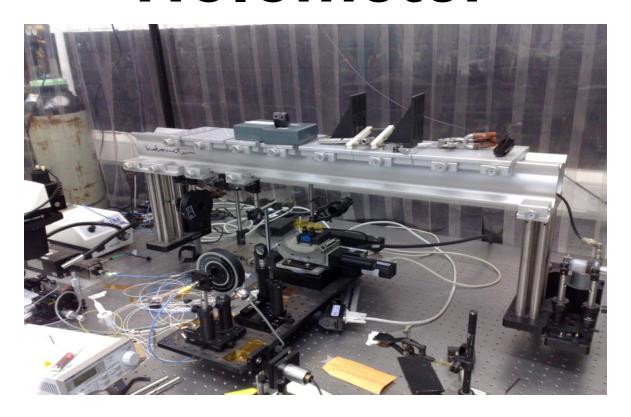
- Before etching: ∆n≈0.05; optical loss 7dB/cm
- After etch + annealing: ∆n ≈1.5; optical loss down to 0.1dB/cm
- Achieved low transmission loss for straight and bent waveguides, inc 24 cm serpentine waveguide

Sensor on a chip



- Low-loss planar optical waveguide devices can be made in the lab
- •Sensor on a chip can be implemented by using evanescent-wave sensing, surface-plasmon resonance sensors, etc.
- (a) Waveguide writing; (b) laser coupling via optical fibre; (c) Top view of our waveguide interferometer; (d) Output at our Y splitter; (e) Evanescent-wave sensing; (f) Sensor on a chip system

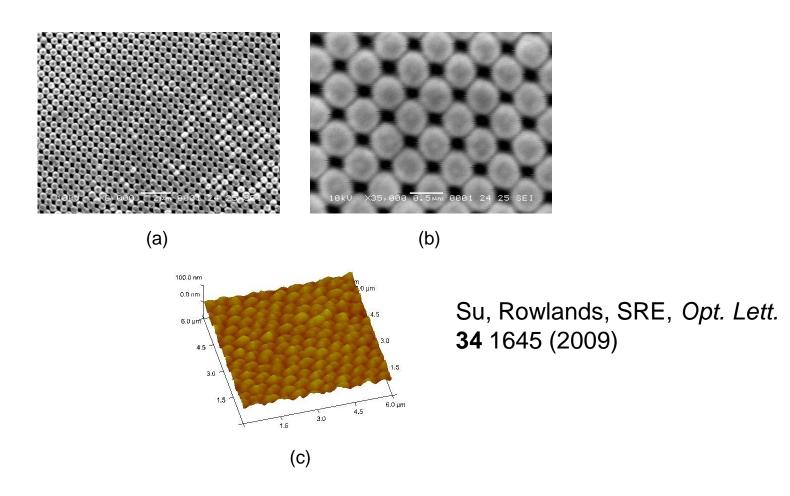
'Holometer'



- 1. Write Bragg grating (parallel-line pattern) 2. Rotate sample by 90°

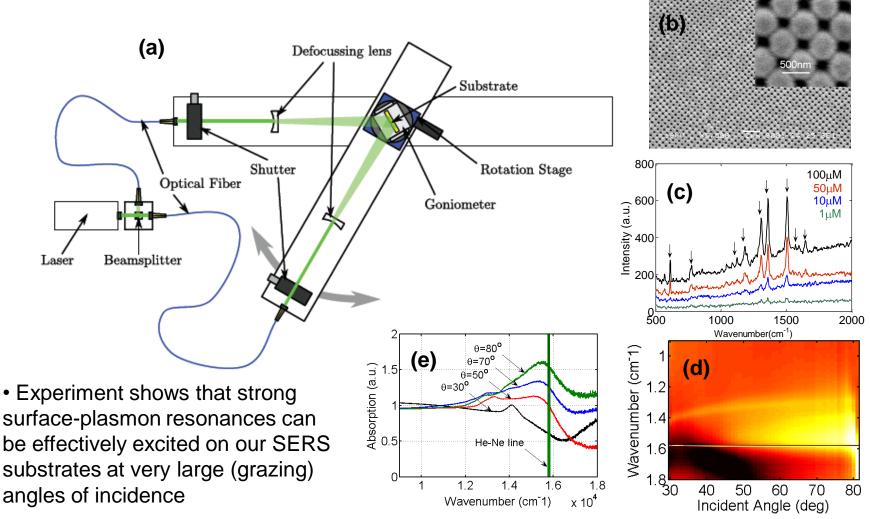
- 3. Write 2nd Bragg grating
- 4. Develop 'checker-board' image using etchant (diisopentylamine in dimethyl sulfoxide)
- 5. Sputter Au film to make SERS substrate

Surface-enhanced Raman scattering (SERS) substrates using chalcogenide glasses (ChG)



(a) and (b) are SEM images of an SERS substrate in ChG at different magnifications; (c) is the AFM image of the same SERS substrate.

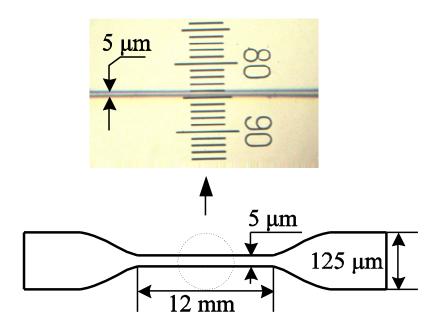
Chalcogenide-resist SERS sensor



- (a) Two-beam interference system; (b) SERS substrate; (c) SERS spectra of R6G;
- (d) Angle-resolved absorption spectra; (e) Cuts on map (d)

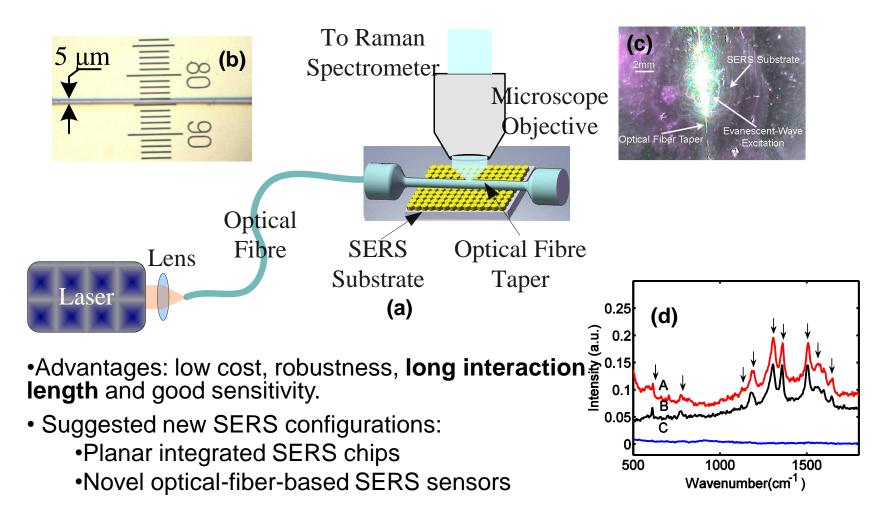
Evanescently excited Raman spectra

Evanescent sensing element



- A thin (5μm) and long (12mm) fibre taper was fabricated from a silica fibre
- Evanescent light field is greatly enhanced along taper

Evanescent-wave SERS sensor



- (a) Configuration; (b) An optical-fibre taper; (c) Experimental photo;
- (d)Experimental results with R6G: A, Evanescent SERS; B, Conventional SERS; C, Control experiment (Su, Lee, SRE, Opt. Lett., **34**, 2685 (2009)

CONCLUSIONS

Chalcogenides exhibit a wide range of:

- Atomic structures
- Physical & chemical behaviour: 'photo-states'
- Applications
- Next Lecture: 'Unstable' glasses & optical computer memories

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